TPS54202 4.5V to 28V Input, 2A Output, EMI Friendly Synchronous Step-Down Converter

1 Features

- 4.5V to 28V wide input voltage range
- Integrated 148mΩ and 78mΩ MOSFETs for 2A, continuous output current
- Low 3µA shutdown, 45µA quiescent current
- Internal 5mS soft start
- Fixed 500kHz switching frequency
- Frequency spread spectrum to reduce EMI
- Advanced Eco-mode™ pulse skip
- Peak current mode control
- Internal loop compensation
- Overcurrent protection for both MOSFETs with hiccup mode protection
- Overvoltage protection
- Thermal shutdown
- SOT-23 (6) package

2 Applications

- 12V, 24V distributed power-bus supply
- Industry application
  - White goods
- Consumer application
  - Audio
  - STB, DTV
  - Printer
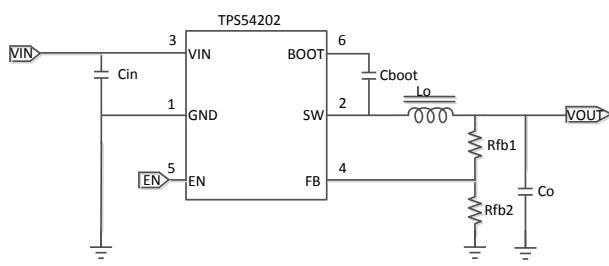
3 Description

The TPS54202 is a 4.5V to 28V input voltage range, 2A synchronous buck converter. The device includes two integrated switching FETs, internal loop compensation and 5ms internal soft start to reduce component count.

By integrating the MOSFETs and employing the SOT-23 package, the TPS54202 achieves the high power density and offers a small footprint on the PCB.

Advanced Eco-mode™ implementation maximizes the light load efficiency and reduces the power loss.

The frequency spread spectrum operation is introduced for EMI reduction.

Cycle-by-cycle current limit in both high-side MOSFET protects the converter in an overload condition and is enhanced by a low-side MOSFET freewheeling current limit which prevents current runaway. Hiccup mode protection is triggered if the overcurrent condition has persisted for longer than the present time.

Package Information

PART NUMBER	PACKAGE[1]	PACKAGE SIZE[2]
TPS54202	DDC (SOT-23, 6)	2.9mm × 2.8mm

(1) For more information, see Section 10.
(2) The package size (length × width) is a nominal value and includes pins, where applicable.

Simplified Schematic
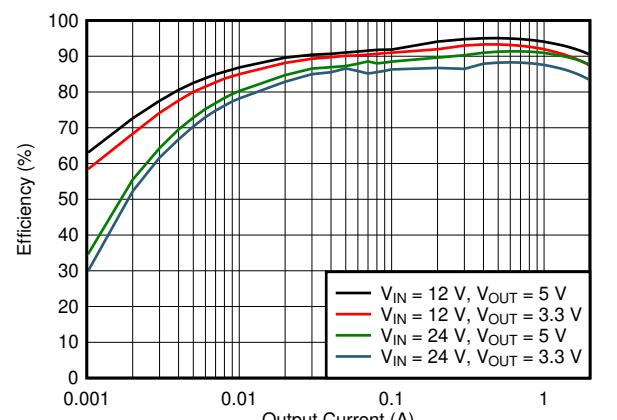
Efficiency vs Output Current

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Product Folder Links: *TPS54202*

4 Pin Configuration and Functions

Figure 4-1. 6-Pin SOT-23 DDC Package (Top View)

Table 4-1. Pin Functions

PIN		TYPE[1]	DESCRIPTION
NAME	NO.		
BOOT	6	O	Supply input for the high-side NFET gate drive circuit. Connect a 0.1µF capacitor between BOOT and SW pins.
EN	5	I	This pin is the enable pin. Float the EN pin to enable.
FB	4	I	Converter feedback input. Connect to output voltage with feedback resistor divider.
GND	1	–	Ground pin. Source terminal of low-side power NFET as well as the ground terminal for controller circuit. Connect sensitive VFB to this GND at a single point.
SW	2	O	Switch node connection between high-side NFET and low-side NFET.
VIN	3	–	Input voltage supply pin. The drain terminal of high-side power NFET.

(1)   O = Output; I = Input

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5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)[1]

		MIN	MAX	UNIT
Input voltage range, V_I	VIN	−0.3	30	V
	EN	−0.3	7	V
	FB	−0.3	7	V
Output voltage range, V_O	BOOT-SW	−0.3	7	V
	SW	−0.3	30	V
	SW (20ns transient)	−5	30	V
Operating junction temperature, T_J		−40	150	°C
Storage temperature range, T_{stg}		−65	150	°C

(1)   Operation outside the *Absolute Maximum Ratings* may cause permanent device damage. *Absolute Maximum Ratings* do not imply functional operation of the device at these or any other conditions beyond those listed under *Recommended Operating Conditions*. If used outside the *Recommended Operating Conditions* but within the *Absolute Maximum Ratings*, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.

5.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001[1]	±2500	V
		Charged-device model (CDM), per JEDEC specification JESD22-C101[2]	±1500	

(1)   JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.
(2)   JEDEC document JEP157 states that 250V CDM allows safe manufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_I	Input voltage range	VIN	4.5	28	V
		EN	−0.1	5.5	V
		FB	−0.1	5.5	V
V_O	Output voltage range	BOOT-SW	−0.1	5.5	V
		SW	−0.1	28	V
T_J	Operating junction temperature		−40	125	°C

5.4 Thermal Information

	THERMAL METRIC[1]	TPS54202 DDC (SOT23) 6 PINS	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance	118.6	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	63.6	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	34.4	°C/W
ψ_{JT}	Junction-to-top characterization parameter	18.5	°C/W
ψ_{JB}	Junction-to-board characterization parameter	33.7	°C/W
$R_{\theta JA\_EVM}$	Junction-to-ambient thermal resistance on official EVM board	57.2	°C/W

(1)   For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application note.

5.5 Electrical Characteristics

The electrical ratings specified in this section apply to all specifications in this document, unless otherwise noted. These specifications are interpreted as conditions that do not degrade the device parametric or functional specifications for the life of the product containing it. T_J = –40°C to +125°C, V_{IN} = 4.5V to 28V, (unless otherwise noted).

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
INPUT SUPPLY						
V_{IN}	Input voltage range		4.5		28	V
I_Q	Non switching quiescent current	EN =5V, VFB = 1V		45		µA
I_{OFF}	Shut down current	EN = GND		3		µA
$V_{IN(UVLO)}$	VIN under voltage lockout	Rising V_{IN}	3.9	4.2	4.4	V
		Falling V_{IN}	3.4	3.7	3.9	V
	Hysteresis		400	480	560	mV
ENABLE (EN PIN)						
$V_{(EN\_RISING)}$	Enable threshold	Rising		1.21	1.28	V
$V_{(EN\_FALLING)}$		Falling	1.1	1.19		V
$I_{(EN\_INPUT)}$	Input current	V_{EN} = 1V		0.7		µA
$I_{(EN\_HYS)}$	Hysteresis current	V_{EN} = 1.5V		1.55		µA
FEEDBACK AND ERROR AMPLIFIER						
V_{FB}	Feedback Voltage	V_{IN} = 12V	0.581	0.596	0.611	V
PULSE SKIP MODE						
$I_{(SKIP)}$ [1]	Pulse skip mode peak inductor current threshold	V_{IN} = 24V, V_{OUT} = 5V, L = 15 µH		300		mA
POWER STAGE						
$R_{(HSD)}$	High-side FET on resistance	T_A = 25°C, V_{BST} – SW = 5V		148		mΩ
$R_{(LSD)}$	Low-side FET on resistance	T_A = 25°C, V_{IN} = 12V		78		mΩ
CURRENT LIMIT						
$I_{(LIM\_HS)}$	High side current limit		2.5	3.2	3.9	A
$I_{(LIM\_LS)}$	Low side source current limit		2	3	4.3	A
OSCILLATOR						
F_{sw}	Centre switching frequency		390	500	630	kHz
OVER TEMPERATURE PROTECTION						
Thermal Shutdown[1]	Rising temperature			160		°C
	Hysteresis			10		°C
	Hiccup time			32768		Cycles

(1)   Not production tested

5.6 Timing Requirements

		MIN	TYP	MAX	UNIT
OVER CURRENT PROTECTION					
t_{HIC_WAIT}	Hiccup up wait time		512		Cycles
$t_{HIC\_RESTART}$	Hiccup up time before restart		16384		Cycles
t_{SS}	Soft-start time		5		mS
ON TIME CONTROL					
t_{MIN_ON} [1]	Minimum on time, measured at 90% to 90% and 1A loading		110		ns

5.7 Typical Characteristics

V_{IN} = 12V, unless otherwise specified
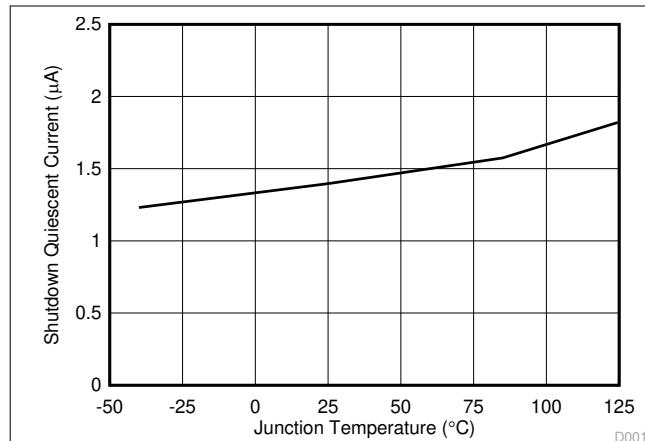
Figure 5-1. Shutdown Quiescent Current vs Junction Temperature
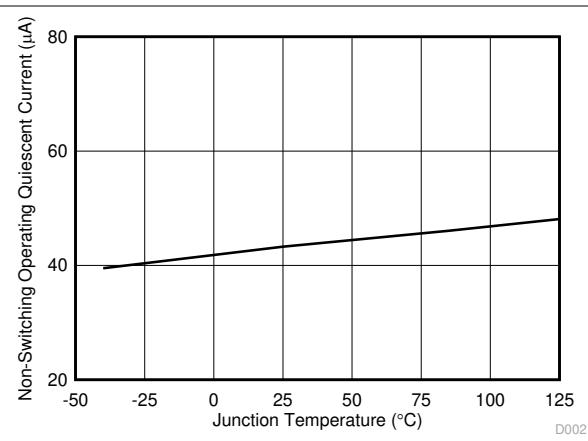

**Figure 5-2. Non-Switching Operating Quiescent Current vs Junction Temperature**
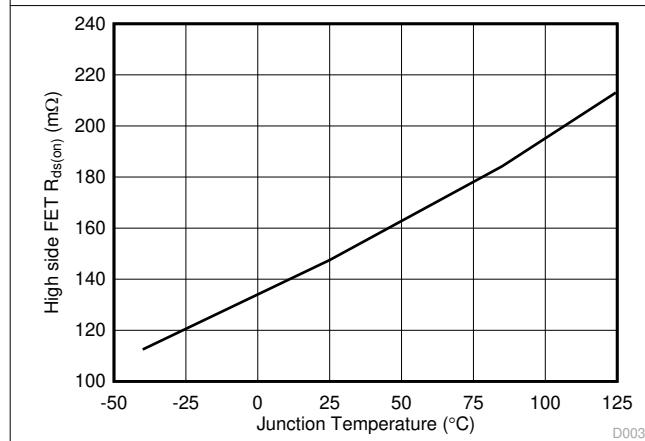
**Figure 5-3. High-Side Resistance vs Junction Temperature**
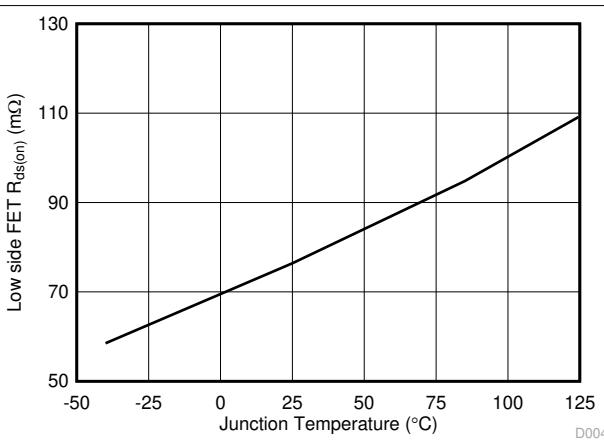
**Figure 5-4. Low-Side FET On Resistance vs Junction Temperature**
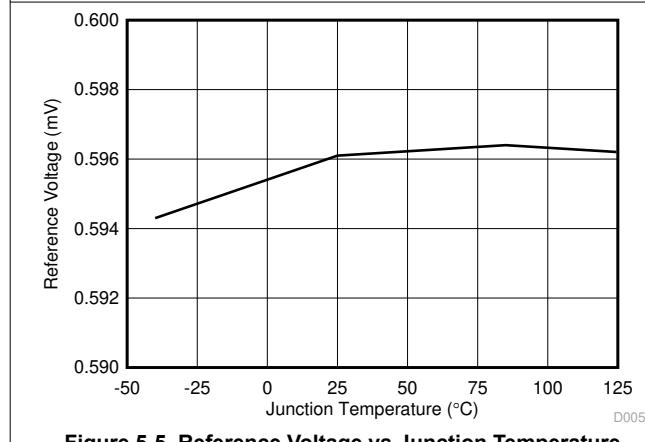
**Figure 5-5. Reference Voltage vs Junction Temperature**
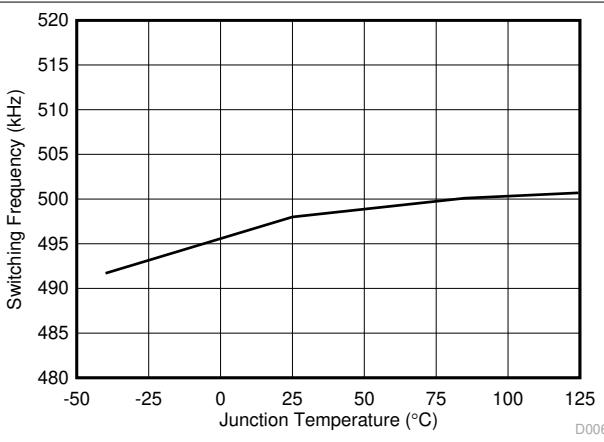
Figure 5-6. Center Switching Frequency vs Junction Temperature

Product Folder Links: *TPS54202*

5.7 Typical Characteristics (continued)

V_{IN} = 12V, unless otherwise specified
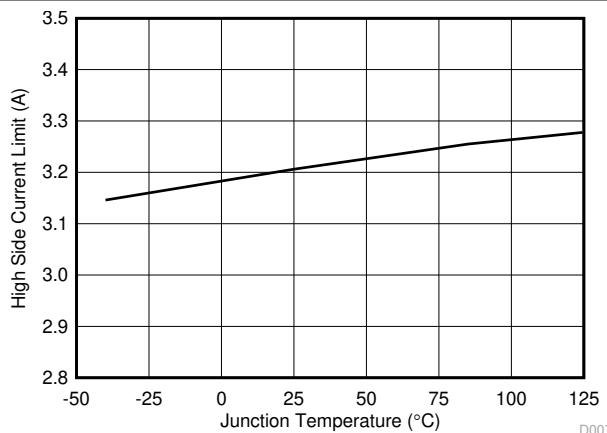
**Figure 5-7. High-Side Current Limit Threshold vs Junction Temperature**
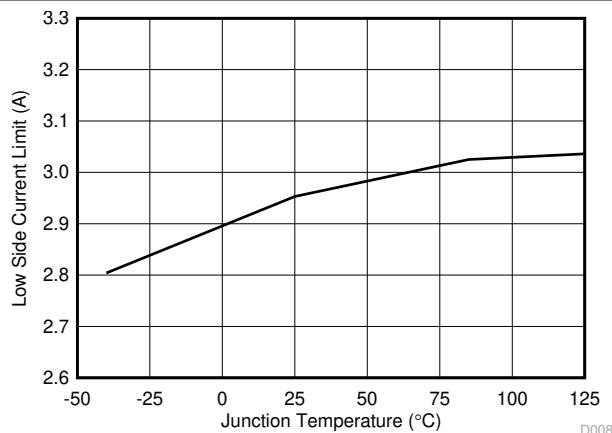
**Figure 5-8. Low-Side Current Limit Threshold vs Junction Temperature**
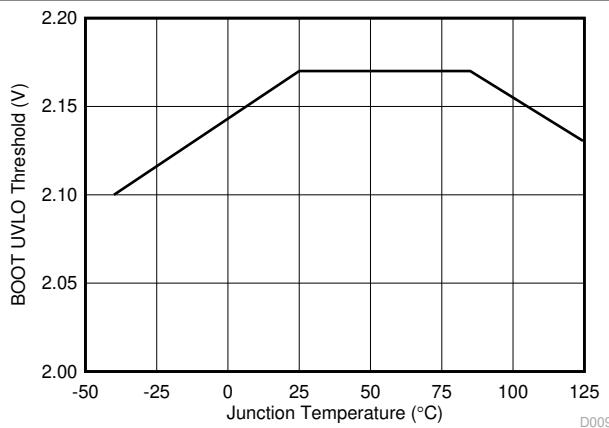
**Figure 5-9. BOOT-SW UVLO Threshold vs Junction Temperature**
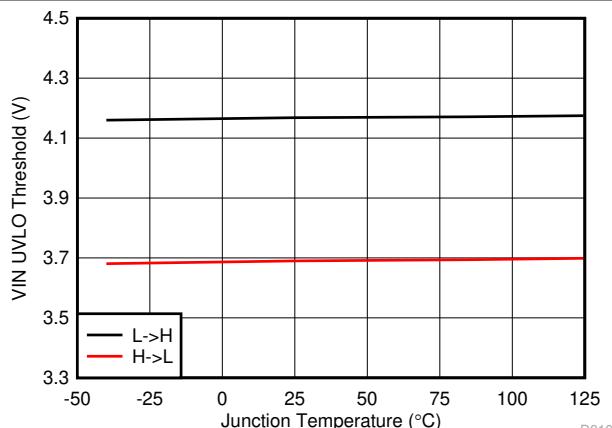

Figure 5-10. VIN UVLO Threshold vs Junction Temperature
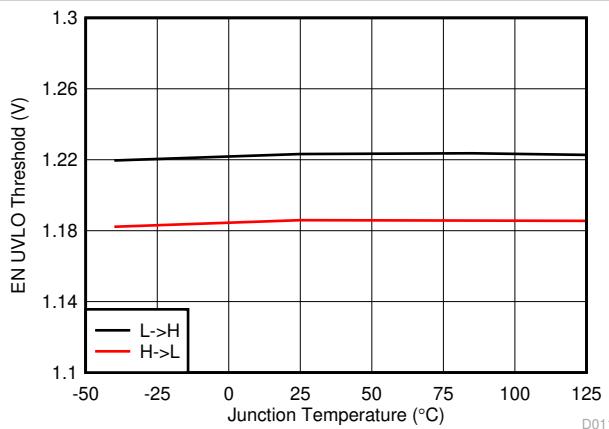
**Figure 5-11. EN Threshold vs Junction Temperature**
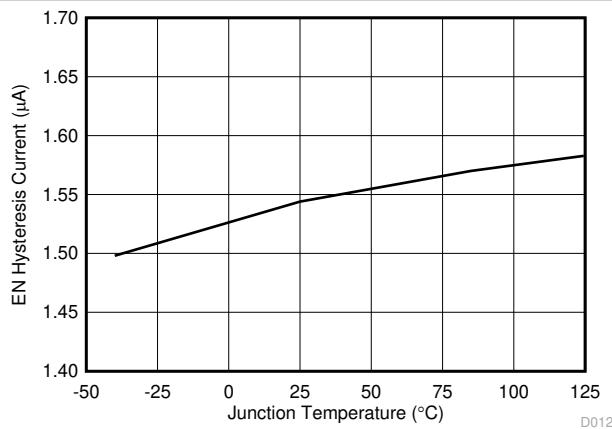
Figure 5-12. EN Hysteresis Current vs Junction Temperature

6 Detailed Description

6.1 Overview

The TPS54202 device is a 28V, 2A, synchronous step-down (buck) converter with two integrated n-channel MOSFETs. To improve performance during line and load transients the device implements a constant-frequency, peak current mode control which reduces output capacitance. The optimized internal compensation network minimizes the external component counts and simplifies the control loop design.

The switching frequency is fixed to 500kHz.

The device begins switching at VIN equal to 4.5V. The operating current is 45µA typically when not switching and under no load. When the device is disabled, the supply current is 3µA typically.

The integrated 148mΩ high-side MOSFET and 78mΩ allow for high efficiency power supply designs with continuous output currents up to 2A.

The device reduces the external component count by integrating the boot recharge diode. The bias voltage for the integrated high-side MOSFET is supplied by an external capacitor on the BOOT to PH pins. The boot capacitor voltage is monitored by an UVLO circuit and turns the high-side MOSFET off when the voltage falls below a preset threshold of 2.1V typically.

The device minimizes excessive output overvoltage transients by taking advantage of the overvoltage comparator. When the regulated output voltage is greater than 108% of the nominal voltage, the overvoltage comparator is activated, and the high-side MOSFET is turned off and masked from turning on until the output voltage is lower than 104%.

The device has internal 5ms soft-start time to minimize inrush currents.

6.2 Functional Block Diagram

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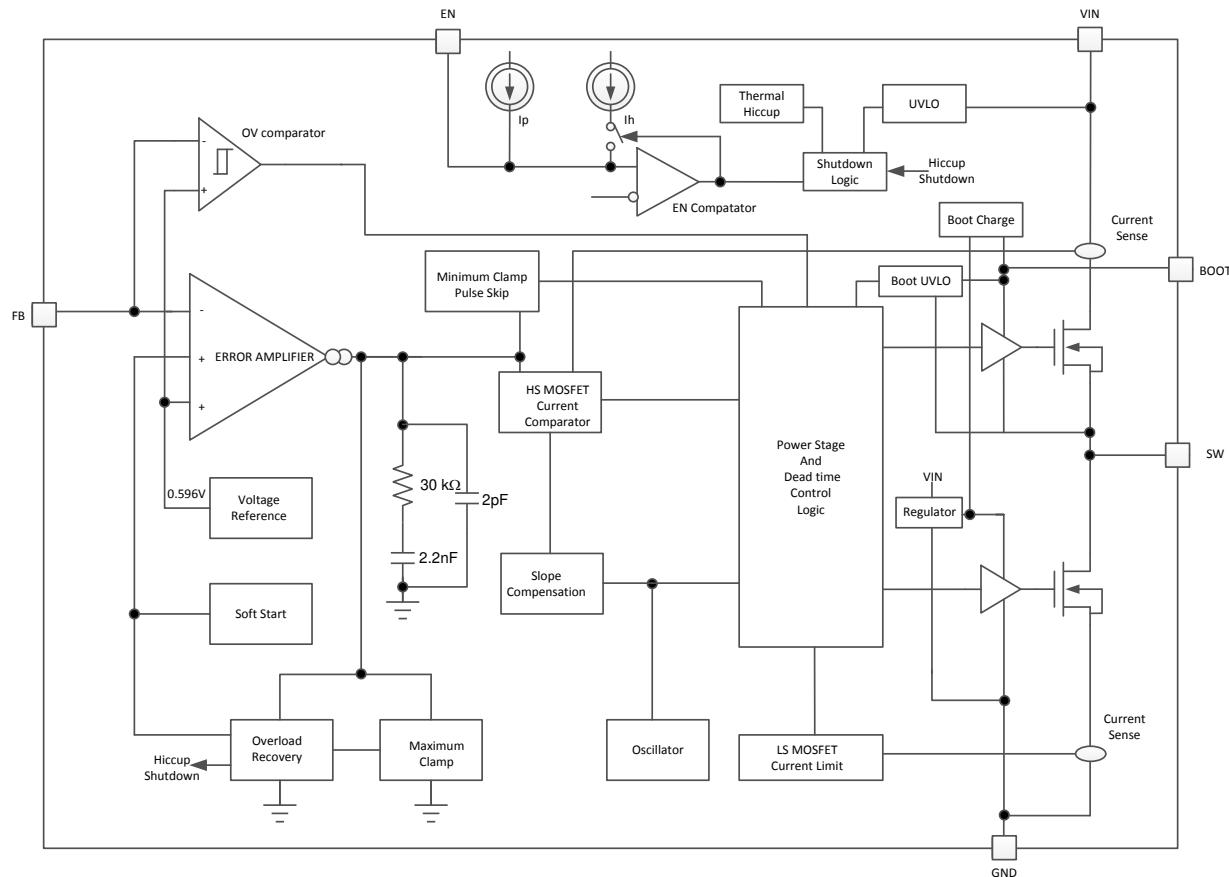
6.3 Feature Description

6.3.1 Fixed-Frequency PWM Control

The device uses a fixed-frequency, peak current-mode control. The output voltage is compared through external resistors on the FB pin to an internal voltage reference by an error amplifier. An internal oscillator initiates the turn on of the high-side power switch. The error amplifier output is compared to the current of the high-side power switch. When the power-switch current reaches the error amplifier output voltage level, the high side power switch is turned off and the low-side power switch is turned on. The error amplifier output voltage increases and decreases as the output current increases and decreases. The device implements a current-limit by clamping the error amplifier voltage to a maximum level and also implements a minimum clamp for improved transient-response performance.

6.3.2 Pulse Skip Mode

The TPS54202 is designed to operate in pulse skipping mode at light load currents to boost light load efficiency. When the peak inductor current is lower than 300mA typically, the device enters pulse skipping mode. When the device is in pulse skipping mode, the error amplifier output voltage is clamped which prevents the high side integrated MOSFET from switching. The peak inductor current must rise above 300mA and exit pulse skip mode. Since the integrated current comparator catches the peak inductor current only, the average load current entering pulse skipping mode varies with the applications and external output filters.

6.3.3 Error Amplifier

The device has a trans-conductance amplifier as the error amplifier. The error amplifier compares the FB voltage to the lower of the internal soft-start voltage or the internal 0.596V voltage reference. The transconductance of the error amplifier is 240µA/V typically. The frequency compensation components are placed internal between the output of the error amplifier and ground.

6.3.4 Slope Compensation and Output Current

The device adds a compensating ramp to the signal of the switch current. This slope compensation prevents sub-harmonic oscillations as the duty cycle increases. The available peak inductor current remains constant over the full duty-cycle range.

6.3.5 Enable and Adjusting Under Voltage Lockout

The EN pin provides electrical on and off control of the device. When the EN pin voltage exceeds the threshold voltage, the device begins operation. If the EN pin voltage is pulled below the threshold voltage, the regulator stops switching and enters the low-quiescent (IQ) state.

The EN pin has an internal pullup-current source which allows the user to float the EN pin to enable the device. If an application requires control of the EN pin, use open-drain or open-collector output logic to interface with the pin.

The device implements internal undervoltage-lockout (UVLO) circuitry on the VIN pin. The device is disabled when the VIN pin voltage falls below the internal VIN UVLO threshold. The internal VIN UVLO threshold has a hysteresis of 480mV.

If an application requires a higher UVLO threshold on the VIN pin, then the EN pin can be configured as shown in Figure 6-1. When using the external UVLO function, setting the hysteresis at a value greater than 500mV is recommended.

The EN pin has a small pull-up current, Ip, which sets the default state of the pin to enable when no external components are connected. The pull-up current is also used to control the voltage hysteresis for the UVLO function because it increases by Ih when the EN pin crosses the enable threshold. Use Equation 1 and Equation 2 to calculate the values of R4 and R5 for a specified UVLO threshold.
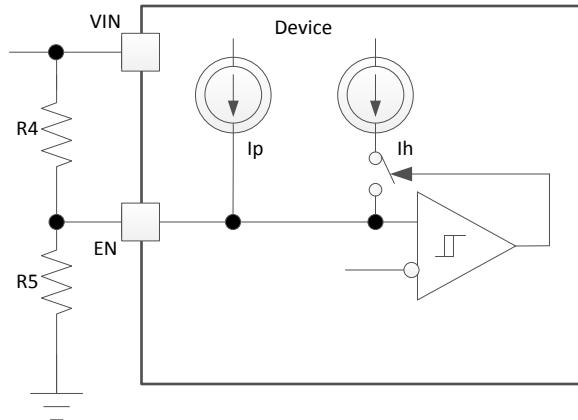
Figure 6-1. Adjustable VIN Undervoltage Lockout

$$R_4 = \frac{\frac{V_{ENfalling}}{V_{ENrising}} \times V_{START} - V_{STOP}}{I_p \times \left(1 - \frac{V_{ENfalling}}{V_{ENrising}}\right) + I_h} \tag{1}$$

$$R_5 = \frac{R_4 \times V_{ENfalling}}{V_{STOP} - V_{ENfalling} + \left(I_h + I_p\right) \times R_4} \tag{2}$$

Where:

- I_p = 0.7µA
- I_h = 1.55µA
- $V_{ENfalling}$ = 1.19V
- $V_{ENrising}$ = 1.21V

6.3.6 Safe Startup into Pre-Biased Outputs

The device has been designed to prevent the low-side MOSFET from discharging a pre-biased output. During monotonic pre-biased startup, both high-side and low-side MOSFETs are not allowed to be turned on until the internal soft-start voltage is higher than FB pin voltage.

6.3.7 Voltage Reference

The voltage reference system produces a precise ±2.5% voltage-reference over temperature by scaling the output of a temperature stable bandgap circuit. The typical voltage reference is designed at 0.596V.

6.3.8 Adjusting Output Voltage

The output voltage is set with a resistor divider from the output node to the FB pin. TI recommends to use divider resistors with 1% tolerance or better. Start with a 100kΩ for the upper resistor divider, use Equation 3 to calculate the output voltage. To improve efficiency at light loads consider using larger value resistors. If the values are too high the regulator is more susceptible to noise and voltage errors from the FB input current are noticeable.

$$V_{OUT} = V_{ref} \times \left(\frac{R_2}{R_3} + 1\right) \tag{3}$$

6.3.9 Internal Soft-Start

The TPS54202 device uses the internal soft-start function. The internal soft start time is set to 5ms typically.

Product Folder Links: *TPS54202*

6.3.10 Bootstrap Voltage (BOOT)

The TPS54202 has an integrated boot regulator and requires a 0.1-µF ceramic capacitor between the BOOT and SW pins to provide the gate drive voltage for the high-side MOSFET. A ceramic capacitor with an X7R or X5R grade dielectric is recommended because of the stable characteristics over temperature and voltage. To improve drop out, the device is designed to operate at 100% duty cycle as long as the BOOT to SW pin voltage is greater than 2.1V typically.

6.3.11 Overcurrent Protection

The device is protected from overcurrent conditions by cycle-by-cycle current limiting on both the high-side MOSFET and the low-side MOSFET.

6.3.11.1 High-Side MOSFET Overcurrent Protection

The device implements current mode control which uses the internal COMP voltage to control the turn off of the high-side MOSFET and the turn on of the low-side MOSFET on a cycle-by-cycle basis. During each cycle, the switch current and the current reference generated by the internal COMP voltage are compared. When the peak switch current intersects the current reference the high-side switch turns off.

6.3.11.2 Low-Side MOSFET Overcurrent Protection

While the low-side MOSFET is turned on, the conduction current is monitored by the internal circuitry. During normal operation the low-side MOSFET sources current to the load. At the end of every clock cycle, the low-side MOSFET sourcing current is compared to the internally set low-side sourcing current-limit. The inductor valley current is exceeded the low-side source current limit, the high-side MOSFET does not turn on and the low-side MOSFET stays on for the next cycle. The high-side MOSFET turns on again when the inductor valley current is below the low-side sourcing current-limit at the start of a cycle as shown in Figure 6-2.
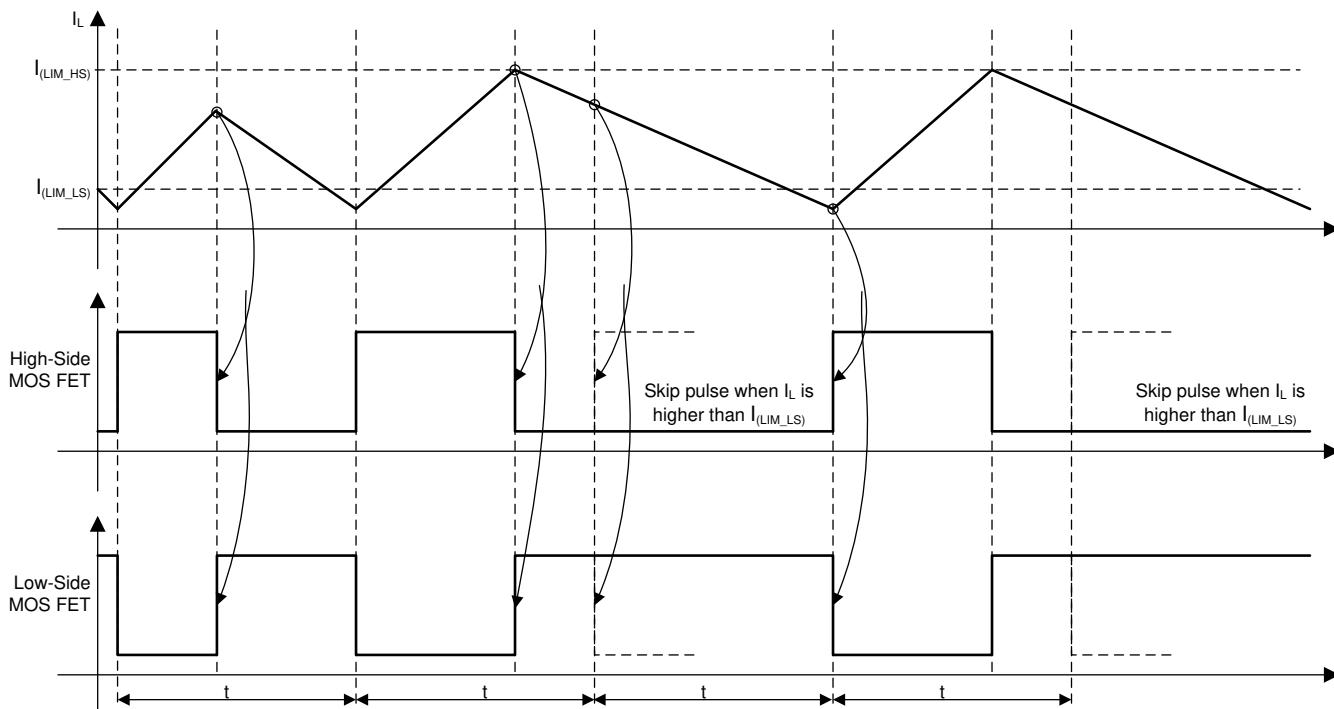

Figure 6-2. Overcurrent Protection for Both MOSFETs

Furthermore, if an output overload condition occurs for more than the hiccup wait time, which is programmed for 512 switching cycles, the device shuts down and restarts after the hiccup time of 16384 cycles. The hiccup mode helps to reduce the device power dissipation under severe overcurrent conditions.

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6.3.12 Spread Spectrum

To reduce EMI, TPS54202 introduces frequency spread spectrum. The jittering span is ±6% of the switching frequency with 1/512 swing frequency.
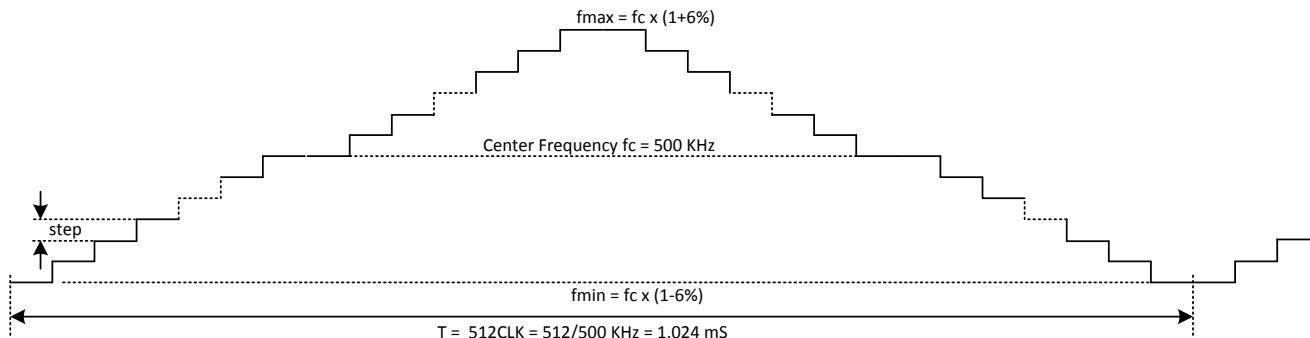

Figure 6-3. Frequency Spread Spectrum Diagram

6.3.13 Output Overvoltage Protection (OVP)

The TPS54202 incorporates an overvoltage transient protection (OVTP) circuit to minimize output voltage overshoot when recovering from output fault conditions or strong unload transients. The OVTP circuit includes an overvoltage comparator to compare the FB pin voltage and internal thresholds. When the FB pin voltage goes above 108% × Vref, the high-side MOSFET is forced off. When the FB pin voltage falls below 104% × Vref, the high-side MOSFET is enabled again.

6.3.14 Thermal Shutdown

The internal thermal-shutdown circuitry forces the device to stop switching if the junction temperature exceeds 155°C typically. When the junction temperature drops below 145°C typically, the internal thermal-hiccup timer begins to count. The device reinitiates the power-up sequence after the built-in thermal-shutdown hiccup time (32768 cycles) is over.

6.4 Device Functional Modes

6.4.1 Normal Operation

When the input voltage is above the UVLO threshold, the TPS54202 can operate in the normal switching modes. Normal continuous conduction mode (CCM) occurs when inductor peak current is above 0A. In CCM, the device operates at a fixed frequency.

6.4.2 Eco-mode™ Operation

The device is designed to operate in high-efficiency pulse-skipping mode under light load conditions. Pulse skipping initiates when the switch current falls to 300mA (typical). During pulse skipping, the low-side FET turns off when the switch current falls to 0A. The switching node (the SW pin) waveform takes on the characteristics of discontinuous conduction mode (DCM) operation and the apparent switching frequency decreases. As the output current decreases, the perceived time between switching pulses increases.

Product Folder Links: *TPS54202*

# 7 Application and Implementation

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Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

7.1 Application Information

The TPS54202 device is typically used as a step-down converter, which converts an input voltage from 8V to 28V to fixed output voltage 5V.

7.2 Typical Application

7.2.1 TPS54202 8V to 28V Input, 5V Output Converter
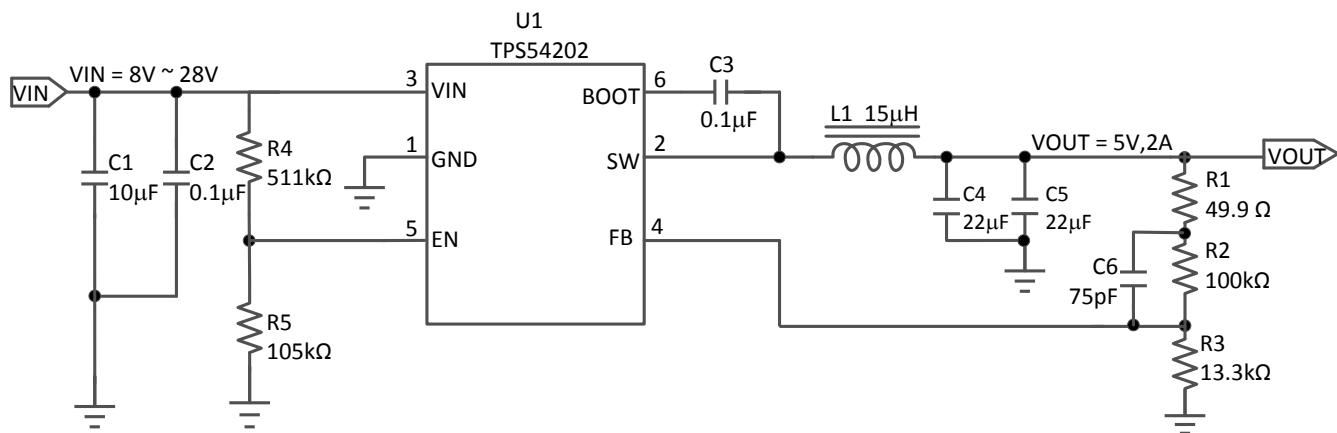
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Figure 7-1. 5V, 2A Reference Design

7.2.2 Design Requirements

For this design example, use the parameters in Table 7-1.

Table 7-1. Design Parameters

PARAMETER	VALUE
Input voltage range	8V to 28V
Output voltage	5V
Output current	2A
Transient response, 1.5A load step	$\Delta V_{OUT} = \pm 5\%$
Input ripple voltage	400mV
Output voltage ripple	30mVpp
Switching frequency	500kHz

7.2.3 Detailed Design Procedure

7.2.3.1 Input Capacitor Selection

The device requires an input decoupling capacitor and a bulk capacitor is needed depending on the application. A ceramic capacitor over 10 µF is recommended for the decoupling capacitor. An additional 0.1 µF capacitor (C2) from VIN to GND is optional to provide additional high frequency filtering. The capacitor voltage rating needs to be greater than the maximum input voltage.

Use Equation 4 to calculate the input ripple voltage (ΔV_{IN}).

$$\Delta V_{IN} = \frac{I_{OUT(MAX)} \times 0.25}{C_{BULK} \times f_{SW}} + I_{OUT(MAX)} \times ESR_{MAX}$$ (4)

where:

- C_{BULK} is the bulk capacitor value
- f_{SW} is the switching frequency
- $I_{OUT(MAX)}$ is the maximum loading current
- ESR_{MAX} is maximum series resistance of the bulk capacitor

The maximum RMS (root mean square) ripple current must also be checked. For worst case conditions, use Equation 5 to calculate $I_{CIN(RMS)}$.

$$I_{CIN(RMS)} = \frac{I_{OUT(MAX)}}{2}$$ (5)

The actual input-voltage ripple is greatly affected by parasitic associated with the layout and the output impedance of the voltage source. Design Requirements show the actual input voltage ripple for this circuit which is larger than the calculated value. This measured value is still below the specified input limit of 400mV. The maximum voltage across the input capacitors is VIN (MAX) + ΔVIN/2. The selected bypass capacitor is rated for 35V and the ripple current capacity is greater than 2A. Both values provide ample margin. The maximum ratings for voltage and current must not be exceeded under any circumstance.

7.2.3.2 Bootstrap Capacitor Selection

A 0.1µF ceramic capacitor must be connected between the BOOT to SW pin for proper operation. TI recommends to use a ceramic capacitor.

7.2.3.3 Output Voltage Set Point

The output voltage of the TPS54202 device is externally adjustable using a resistor divider network. In the application circuit of Figure 7-1 , this divider network is comprised of R2 and R3. Use Equation 6 and Equation 7 to calculate the relationship of the output voltage to the resistor divider.

$$R_3 = \frac{R_2 \times V_{ref}}{V_{OUT} - V_{ref}}$$ (6)

$$V_{OUT} = V_{ref} \times \left(\frac{R_2}{R_3} + 1\right)$$ (7)

Select a value of R2 to be approximately 100kΩ. Slightly increasing or decreasing R3 can result in closer output voltage matching when using standard value resistors. In this design, R2 = 100kΩ and R3 = 13.3kΩ which results in a 5V output voltage. The 49.9Ω resistor, R1, is provided as a convenient location to break the control loop for stability testing.

7.2.3.4 Undervoltage Lockout Set Point

The undervoltage lockout (UVLO) set point can be adjusted using the external-voltage divider network of R4 and R5. R4 is connected between the VIN and EN pins of the TPS54202 device. R5 is connected between the EN and GND pins. The UVLO has two thresholds, one for power up when he input voltage is rising and one for

power down or brown outs when the input voltage is falling. Use Equation 1 and Equation 2 to calculate the values for the upper and lower resistor values of R4 and R5.

7.2.3.5 Output Filter Components

Two components must be selected for the output filter, the output inductor (L_O) and C_O.

7.2.3.5.1 Inductor Selection

Use Equation 8 to calculate the minimum value of the output inductor (L_{MIN}).

$$L_{MIN} = \frac{V_{OUT} \times \left[V_{IN(MAX)} - V_{OUT} \right]}{V_{IN(MAX)} \times K_{IND} \times I_{OUT} \times f_{SW}}$$

(8)

Where:

K_{IND} is a coefficient that represents the amount of inductor ripple current relative to the maximum output current.

In general, the value of K_{IND} is at the discretion of the designer; however, the following guidelines can be used. For designs using low-ESR output capacitors, such as ceramics, a value as high as $K_{IND} = 0.3$ can be used. When using higher ESR output capacitors, $K_{IND} = 0.2$ yields better results.

For this design example, use $K_{IND} = 0.3$. The minimum inductor value is calculated as 13.7µH. For this design, a close standard value of 15µH was selected for L_{MIN}.

For the output filter inductor, the RMS current and saturation current ratings must not be exceeded. Use Equation 9 to calculate the RMS inductor current ($I_{L(RMS)}$).

$$I_{L(MAX)} = \sqrt{I_{OUT(MAX)}^2 + \frac{1}{12} \times \left[\frac{V_{OUT} \times \left(V_{IN(MAX)} - V_{OUT} \right)}{V_{IN(MAX)} \times L_O \times f_{SW} \times 0.8} \right]^2}$$

(9)

Use Equation 10 to calculate the peak inductor current ($I_{L(PK)}$).

$$I_{L(PK)} = I_{OUT(MAX)} + \frac{V_{OUT} \times \left[V_{IN(MAX)} - V_{OUT} \right]}{V_{IN(MAX)} \times L_O \times f_{SW} \times 1.6}$$

(10)

Smaller or larger inductor values can be used depending on the amount of ripple current the designer wants to allow so long as the other design requirements are met. Larger value inductors have lower AC current and result in lower output voltage ripple. Smaller inductor values increase AC current and output voltage ripple.

7.2.3.5.2 Output Capacitor Selection

Consider three primary factors when selecting the value of the output capacitor. The output capacitor determines the modulator pole, the output voltage ripple, and how the regulator responds to a large change in load current. The output capacitance must be selected based on the more stringent of these three criteria.

The desired response to a large change in the load current is the first criterion. The output capacitor must supply the load with current when the regulator cannot. This situation occurs if the desired hold-up times are present for the regulator. In this case, the output capacitor must hold the output voltage above a certain level for a specified amount of time after the input power is removed. The regulator is also temporarily unable to supply sufficient output current if a large, fast increase occurs affecting the current requirements of the load, such as a transition from no load to full load. The regulator usually requires two or more clock cycles for the control loop to notice the change in load current and output voltage and to adjust the duty cycle to react to the change. The output capacitor must be sized to supply the extra current to the load until the control loop responds to the load change. The output capacitance must be large enough to supply the difference in current for 2 clock cycles while only allowing a tolerable amount of drop in the output voltage. Use Equation 11 to calculate the minimum required output capacitance.

$$C_O = \frac{2 \times \Delta I_{OUT}}{f_{SW} \times \Delta V_{OUT}}$$

(11)

where:

- ΔI_{OUT} is the change in output current
- f_{SW} is the switching frequency of the regulator
- $\Delta V_{(OUT)}b$ is the allowable change in the output voltage

For this example, the transient load response is specified as a 5% change in the output voltage, V_{OUT}, for a load step of 1.5A. For this example, ΔI_{OUT} = 1.5A and ΔV_{OUT} = 0.05 × 5 = 0.25V. Using these values results in a minimum capacitance of 24µF. This value does not consider the ESR of the output capacitor in the output voltage change. For ceramic capacitors, the ESR is usually small enough to ignore in this calculation.

Equation 12 calculates the minimum output capacitance required to meet the output voltage ripple specification. In this case, the maximum output voltage ripple is 30mV. Under this requirement, Equation 12 yields 4.56µF.

$$C_O = \frac{1}{8 \times f_{SW}} \times \frac{1}{\frac{V_{OUTripple}}{I_{ripple}}} \qquad (12)$$

where:

- f_{SW} is the switching frequency
- $V_{(OUTripple)}$ is the maximum allowable output voltage ripple
- $I_{(ripple)}$ is the inductor ripple current

Use Equation 13 to calculate the maximum ESR an output capacitor can have to meet the output-voltage ripple specification. Equation 13 indicates the ESR must be less than 54.8mΩ. In this case, the ESR of the ceramic capacitor is much smaller than 54.8mΩ.

$$R_{ESR} < \frac{V_{OUTripple}}{I_{ripple}} \qquad (13)$$

The output capacitor can affect the crossover frequency f_o. Considering to the loop stability and effect of the internal parasitic parameters, choose the crossover frequency less than 40kHz without considering the feed forward capacitor. A simple estimation for the crossover frequency without feed forward capacitor C6 is shown in Equation 14, assuming C_{OUT} has small ESR.

$$f_O = \frac{3.95}{V_{OUT} \times C_{OUT}} \qquad (14)$$

Additional capacitance deratings for aging, temperature, and DC bias must be considered which increases this minimum value. For this example, two 22uF 25V, X7R ceramic capacitors are used. Capacitors generally have limits to the amount of ripple current they can handle without failing or producing excess heat. An output capacitor that can support the inductor ripple current must be specified. Some capacitor data sheets specify the RMS value of the maximum ripple current. Use Equation 15 to calculate the RMS ripple current that the output capacitor must support. For this application, Equation 15 yields 79mA for each capacitor.

$$I_{COUT(RMS)} = \frac{1}{\sqrt{12}} \times \left[\frac{V_{OUT} \times \left(V_{IN(MAX)} - V_{OUT}\right)}{V_{IN(MAX)} \times L_O \times f_{SW} \times N_C} \right] \qquad (15)$$

7.2.3.5.3 Feed-Forward Capacitor

The TPS54202 device is internally compensated and the internal compensation network is composed of two capacitors and one resister shown on the block diagram. Depending on the V_{OUT}, if the output capacitor C_{OUT} is dominated by low ESR (ceramic types) capacitors, this action can result in low phase margin. To improve the phase boost an external feedforward capacitor C6 can be added in parallel with R2. C6 is chosen such that phase margin is boosted at the crossover frequency.

Equation 16 for C6 is tested:

$$C6 = \frac{1}{2\pi f_O} \times \frac{1}{R2} \tag{16}$$

For this design, C6 = 75pF. C6 is not needed when C_{OUT} has high ESR, and C6 calculated from Equation 16 must be reduced with medium ESR. Table 7-2 can be used as a starting point.

Table 7-2. Recommended Component Values

V_{OUT} (V)	L (µH)[1]	C_{OUT}(µF)	R2 (kΩ)	R3 (kΩ)	C6 (pF)
1.8	5.6	66	100	49.9	47
2.5	8.2	44	100	31.6	33
3.3	10	44	100	22.1	56
5	15	44	100	13.3	75
12	22	44	100	5.23	100

(1)   Based on VIN = 28V

Product Folder Links: TPS54202

7.2.4 Application Curves
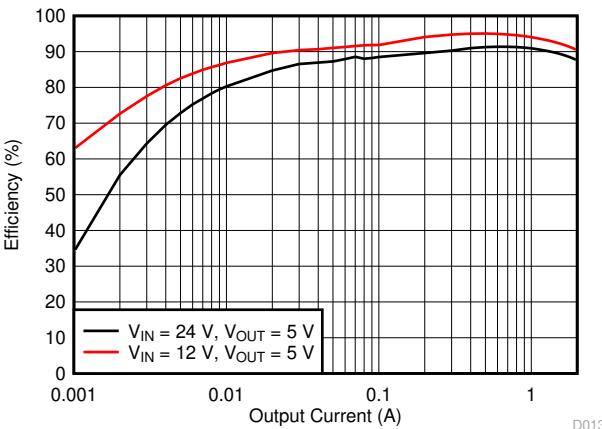
Figure 7-2. Efficiency
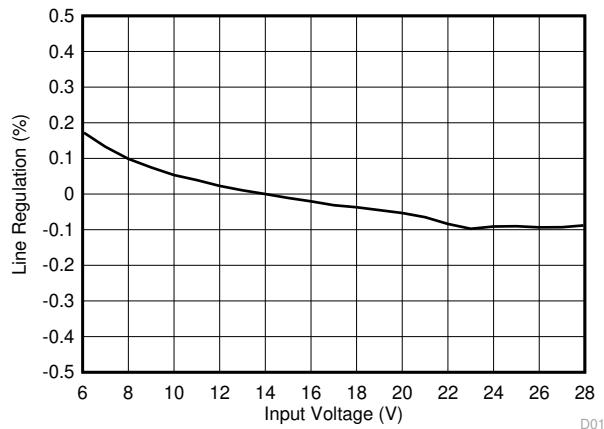
Figure 7-3. Line Regulation
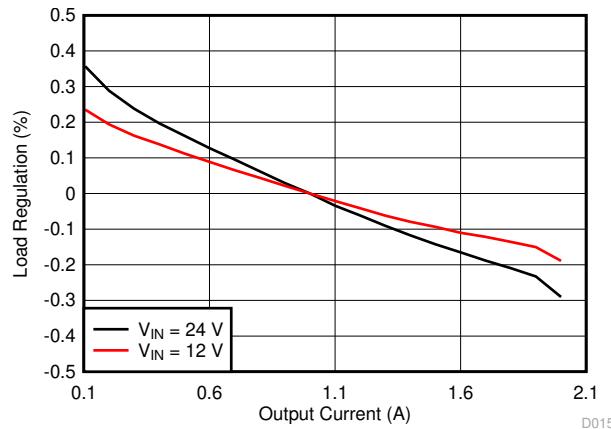
Figure 7-4. Load Regulation

V_{OUT} = 200 mV/div (ac coupled)

PH = 10 V/div

Time - 2 µs/div
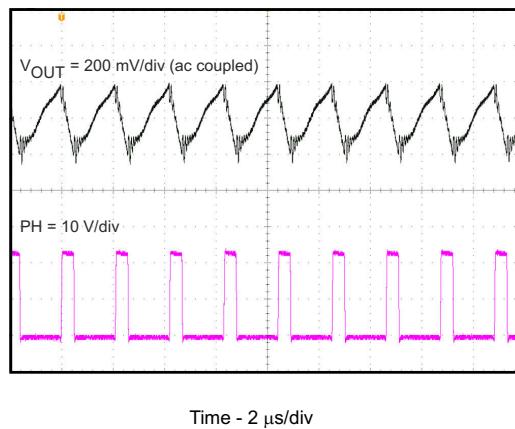
I_{OUT} = 2A

Figure 7-5. Input Voltage Ripple

V_{OUT} = 20 mV/div (ac coupled)

PH = 10 V/div

Time - 4 ms/div

I_{OUT} = 0A
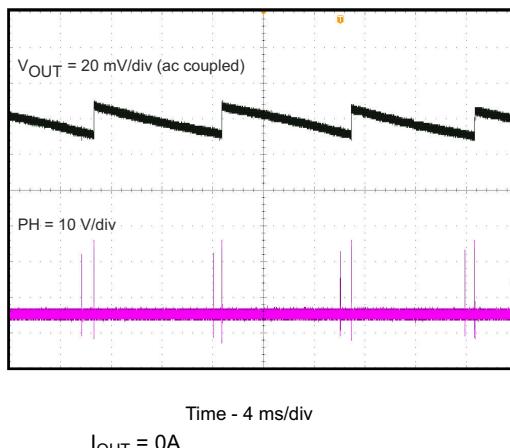
Figure 7-6. Output Voltage Ripple

V_{OUT} = 20 mV/div (ac coupled)

PH = 10 V/div

Time - 40 µs/div
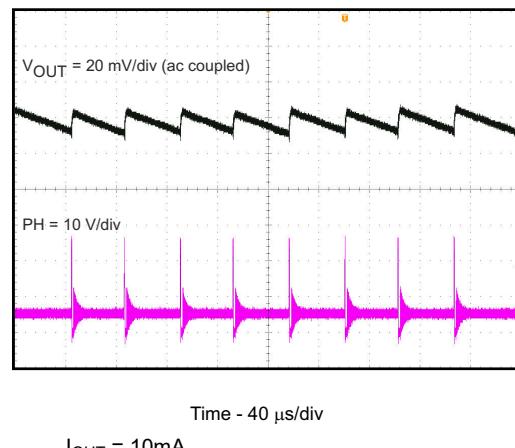
I_{OUT} = 10mA

Figure 7-7. Output Voltage Ripple

Product Folder Links: *TPS54202*
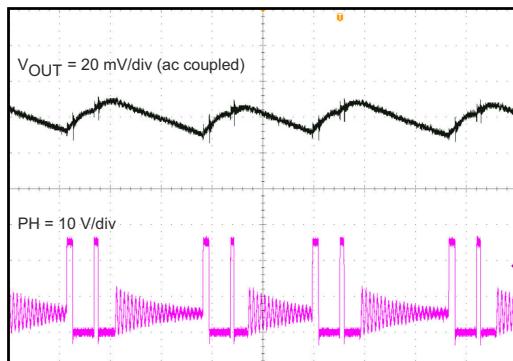
Time - 4 µs/div

I_{OUT} = 100mA

Figure 7-8. Output Voltage Ripple
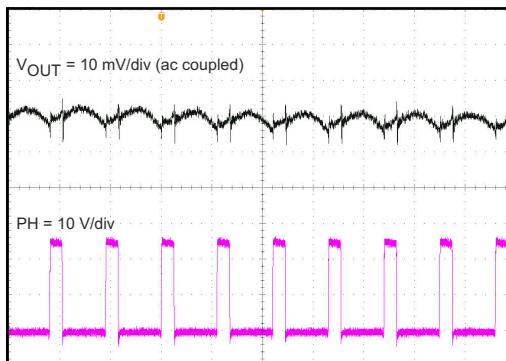
Time - 2 µs/div

I_{OUT} = 2A

Figure 7-9. Output Voltage Ripple
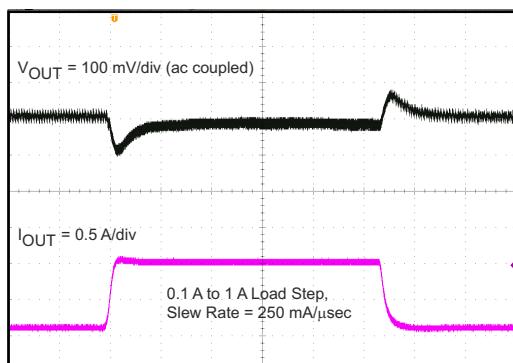
Time - 200 µs/div

0.1 to 1A

Figure 7-10. Transient Response
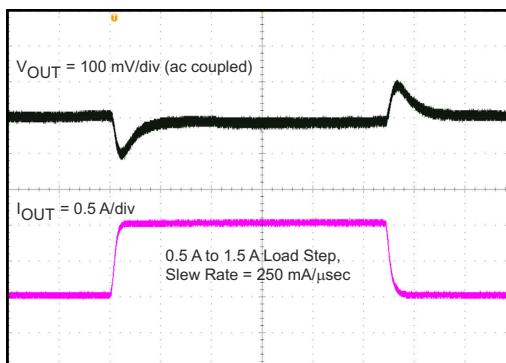
Time - 200 µs/div

0.5 to 1.5A

Figure 7-11. Transient Response
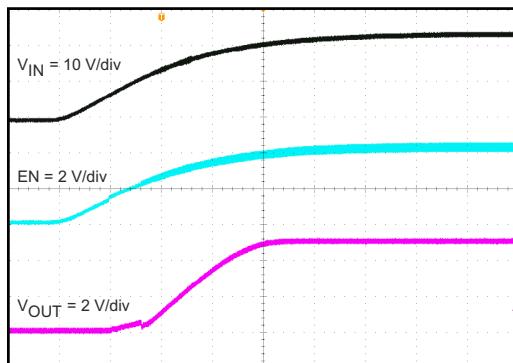
Time - 2 ms/div

Figure 7-12. Start-Up Relative to VIN
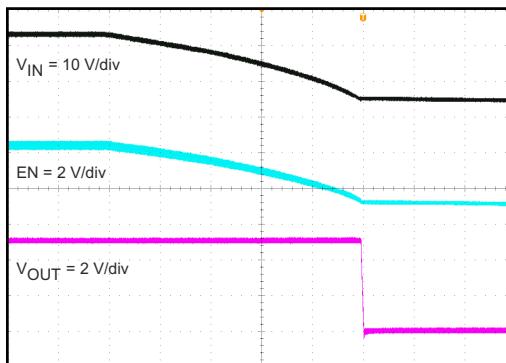
Time - 2 ms/div

Figure 7-13. Shutdown Relative to VIN
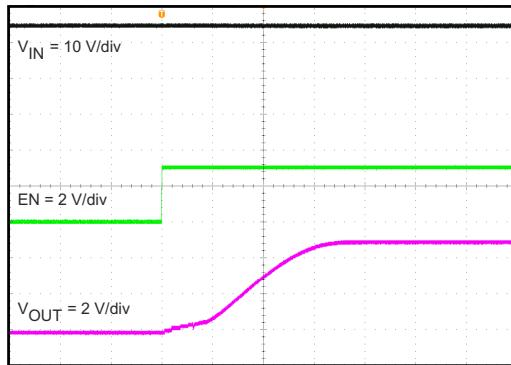
Figure 7-14. Start-Up Relative to EN
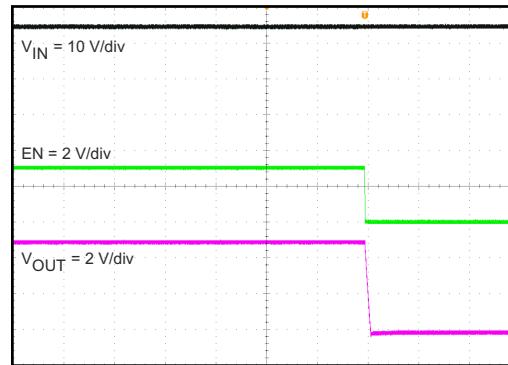
Figure 7-15. Shutdown Relative to EN

7.3 Power Supply Recommendations

The devices are designed to operate from an input voltage supply range between 4.5V and 28V. This input supply must be well regulated. If the input supply is located more than a few inches from the device or converter, additional bulk capacitance can be required in addition to the ceramic bypass capacitors. An electrolytic capacitor with a value of 47μF is a typical choice.

7.4 Layout

7.4.1 Layout Guidelines

- VIN and GND traces must be as wide as possible to reduce trace impedance. The wide areas are also of advantage from the view point of heat dissipation.
- The input capacitor and output capacitor must be placed as close to the device as possible to minimize trace impedance.
- Provide sufficient vias for the input capacitor and output capacitor.
- Keep the SW trace as physically short and wide as practical to minimize radiated emissions.
- Do not allow switching current to flow under the device.
- A separate VOUT path must be connected to the upper feedback resistor.
- Make a Kelvin connection to the GND pin for the feedback path.
- Voltage feedback loop must be placed away from the high-voltage switching trace, and preferably has ground shield.
- The trace of the VFB node must be as small as possible to avoid noise coupling.
- The GND trace between the output capacitor and the GND pin must be as wide as possible to minimize its trace impedance.

Product Folder Links: *TPS54202*

7.4.2 Layout Example
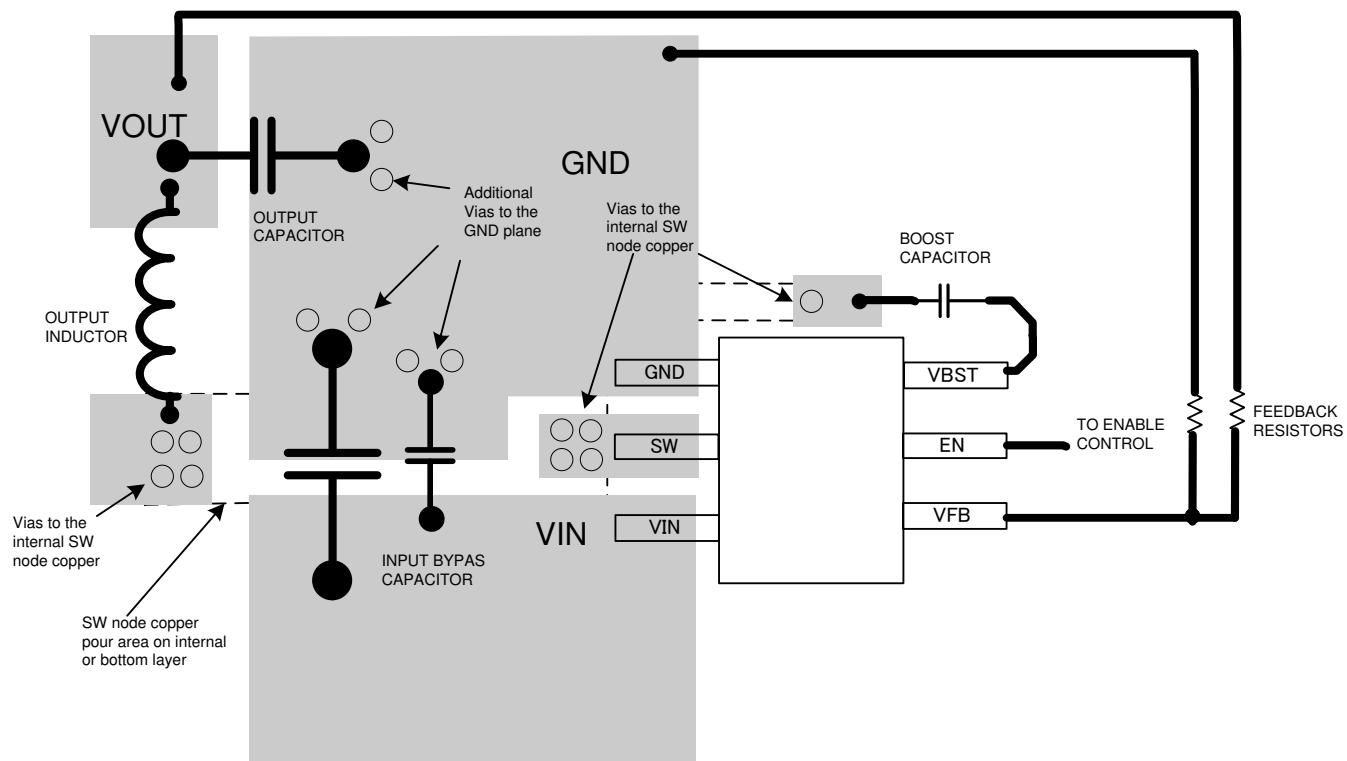
Figure 7-16. Board Layout

8 Device and Documentation Support

8.1 Device Support

8.1.1 Third-Party Products Disclaimer

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8.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

8.3 Support Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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8.5 Electrostatic Discharge Caution

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

8.6 Glossary

TI Glossary   This glossary lists and explains terms, acronyms, and definitions.

9 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGE OPTION ADDENDUM

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TPS54202DDCR	Active	Production	SOT-23-THIN (DDC) | 6	3000 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	4202
TPS54202DDCR.A	Active	Production	SOT-23-THIN (DDC) | 6	3000 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	4202
TPS54202DDCR.B	Active	Production	SOT-23-THIN (DDC) | 6	3000 | LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	4202
TPS54202DDCT	Active	Production	SOT-23-THIN (DDC) | 6	250 | SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	4202
TPS54202DDCT.A	Active	Production	SOT-23-THIN (DDC) | 6	250 | SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	4202
TPS54202DDCT.B	Active	Production	SOT-23-THIN (DDC) | 6	250 | SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	4202

(1) Status: For more details on status, see our product life cycle.

(2) Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION

REEL DIMENSIONS
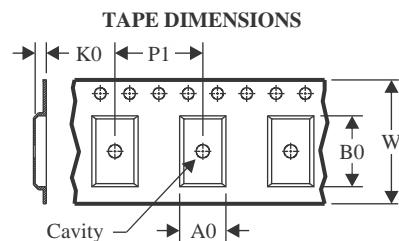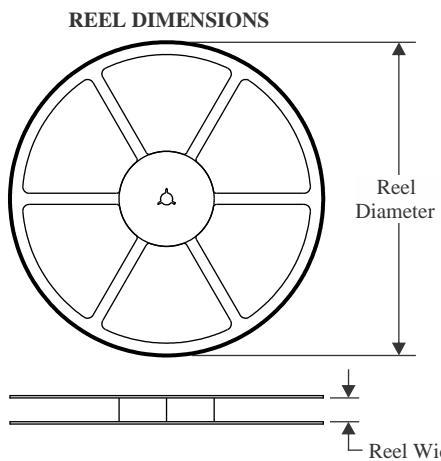
**TAPE DIMENSIONS**

A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE
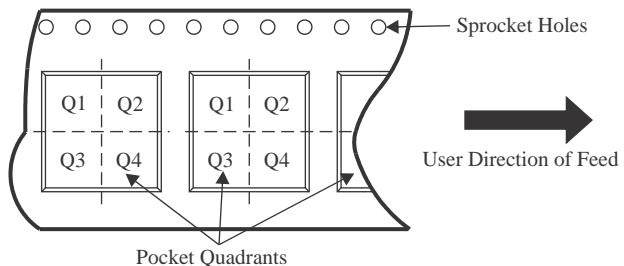
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS54202DDCR	SOT-23-THIN	DDC	6	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS54202DDCT	SOT-23-THIN	DDC	6	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3

PACKAGE MATERIALS INFORMATION

TAPE AND REEL BOX DIMENSIONS

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS54202DDCR	SOT-23-THIN	DDC	6	3000	210.0	185.0	35.0
TPS54202DDCT	SOT-23-THIN	DDC	6	250	210.0	185.0	35.0

4214841/E   08/2024
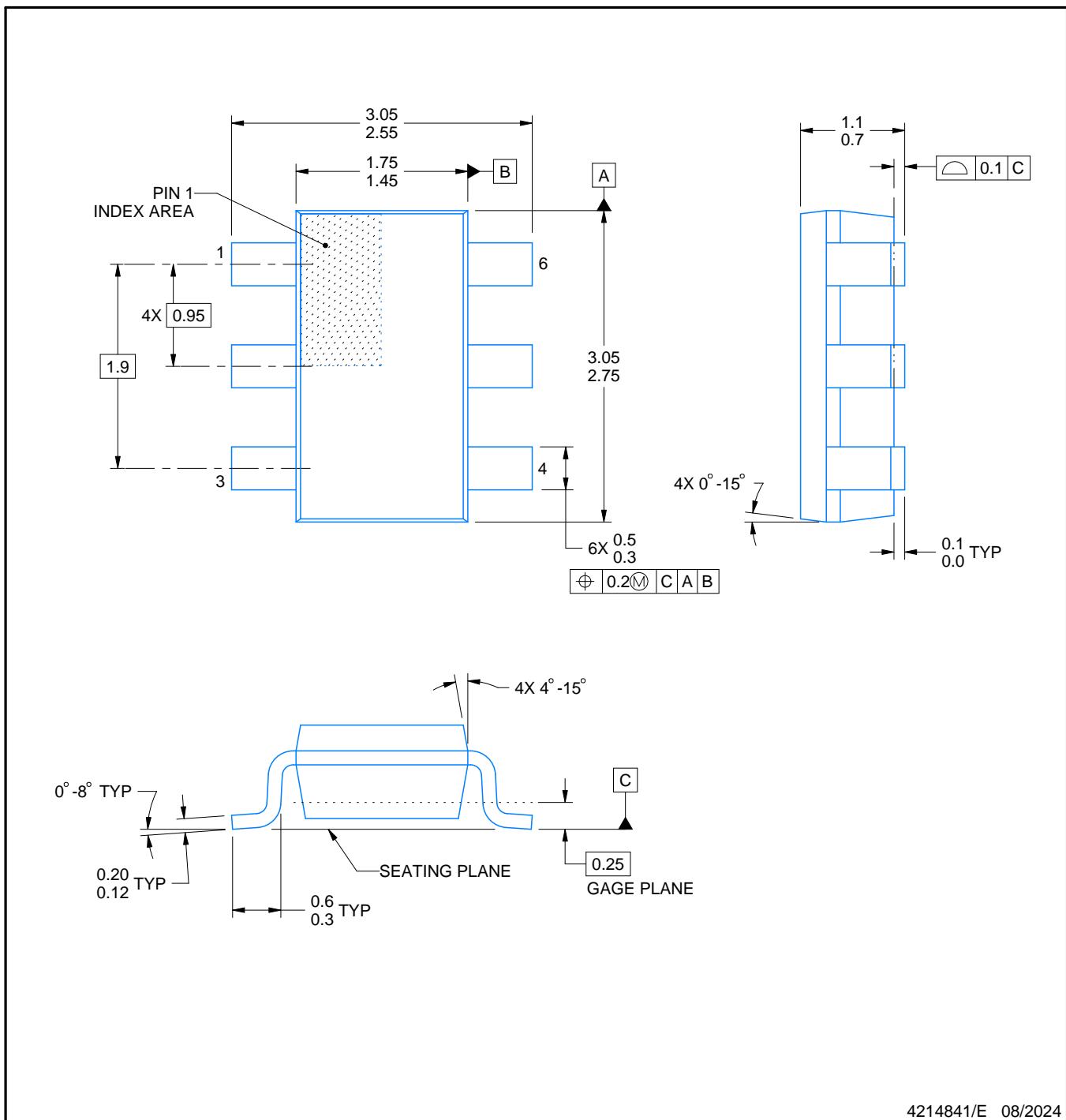
NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC MO-193.

6X (1.1)

SYMM

1

6X (0.6)

6

SYMM

4X (0.95)

3

4

(R0.05) TYP

(2.7)
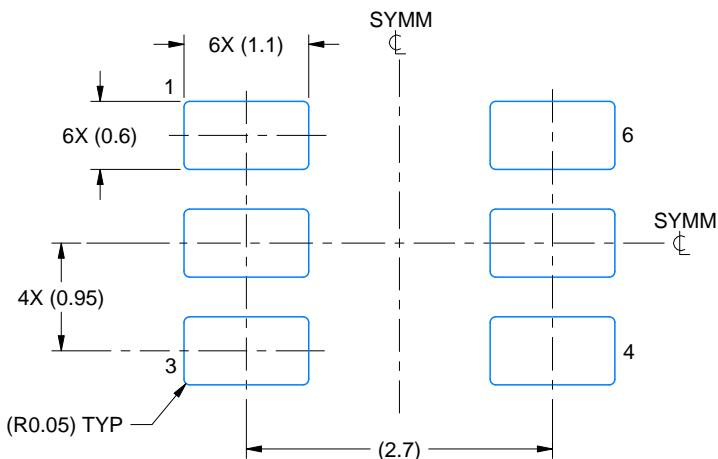
LAND PATTERN EXAMPLE
EXPLOSED METAL SHOWN
SCALE:15X

SOLDER MASK
OPENING

METAL

EXPOSED METAL

0.07 MAX
ARROUND

NON SOLDER MASK
DEFINED

METAL UNDER
SOLDER MASK

SOLDER MASK
OPENING

EXPOSED METAL

0.07 MIN
ARROUND

SOLDER MASK
DEFINED
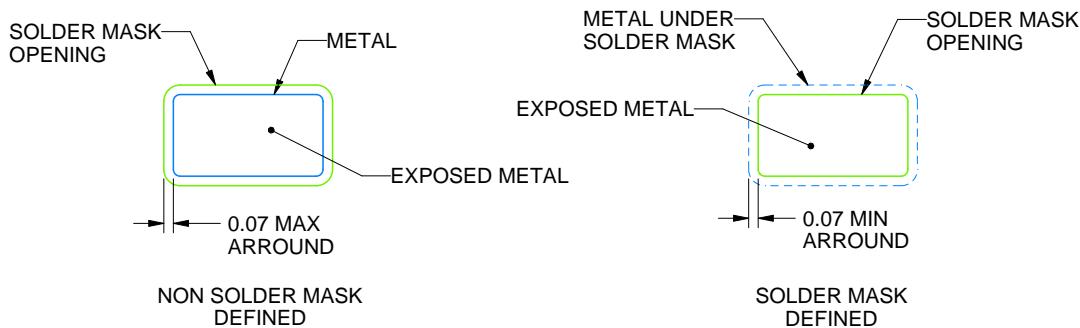
SOLDERMASK DETAILS

4214841/E   08/2024

NOTES: (continued)

4. Publication IPC-7351 may have alternate designs.
5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

SYMM

6X (1.1)

1

6X (0.6)

SYMM

6

4X(0.95)

3

4

(R0.05) TYP

(2.7)
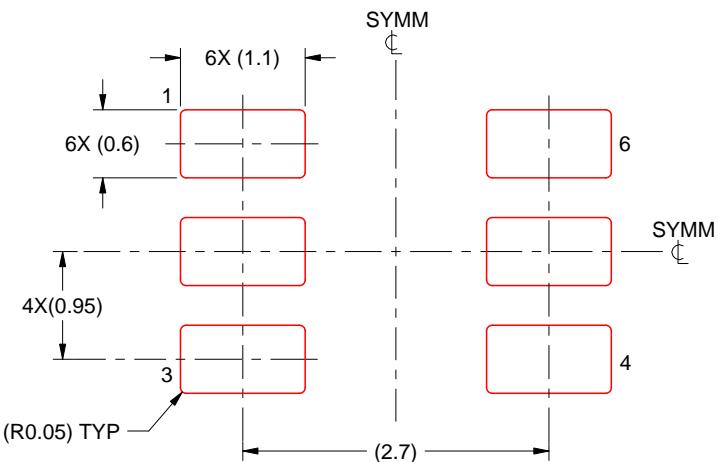
SOLDER PASTE EXAMPLE
BASED ON 0.125 THICK STENCIL
SCALE:15X

4214841/E 08/2024

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
7. Board assembly site may have different recommendations for stencil design.

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